1. (Currently Amended) A current driving apparatus for an active matrix organic light

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emitting diode (AMOLED), which utilizes two abutting sub-pixels, (an the two abutting sub-

pixels being an odd sub-pixel and an even sub-pixel). The-, said abutting sub-pixels sharing a

data line, a scan line and a common line, the driving apparatus of each sub-pixel-includes

comprising:

odd a line enable, the line enable being an odd line enable for the odd sub-pixels[[;]] and

an even line enable for the even sub-pixels;

a data line shared by the odd sub-pixels and the even sub-pixels;

a sean line;

a supply line;

a common line;

a writing element with the having a source that connects to the data line;

a switching element with the having a gate that connects to the gate of the writing

element; and the source a source that connects to the data line;

a driving element with the having a gate that connects to the drain of the writing element;

and the a source connects to the supply line;

a control element with the having a gate that connects to the scan line; and the source a

source that connects to the odd line enable (even-line enable); and the drain a drain that connects

to the gate of the switching element;

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a storage element with having two ends, one end connected to the source of the

driving element; and the other end connects connected to the connection of the gate of the

driving element and the drain of the writing element; and

a light emission element with having two ends, one end is being the positive electrode

that connects to the drain of the driving element; and the other end is being the negative

electrode that connects to the common line.

2. (Currently Amended) As the The current driving apparatus for an active matrix organic

light emitting diode of claim 1, wherein the writing element is a thin film transistor.

3. (Currently Amended) As the The current driving apparatus for an active matrix organic

light emitting diode of claim 1, wherein the switching element is a thin film transistor.

4. (Currently Amended) As the The current driving apparatus for an active matrix organic

light emitting diode of claim 1, wherein the driving element is a thin film transistor.

5. (Currently Amended) As the The current driving apparatus for an active matrix organic

light emitting diode of claim 1, wherein the control element is a thin film transistor.

6. (Currently Amended) As the The current driving apparatus for an active matrix organic

light emitting diode of claim 1, wherein the storage element is a storage capacitor.

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7. (Cancelled)

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